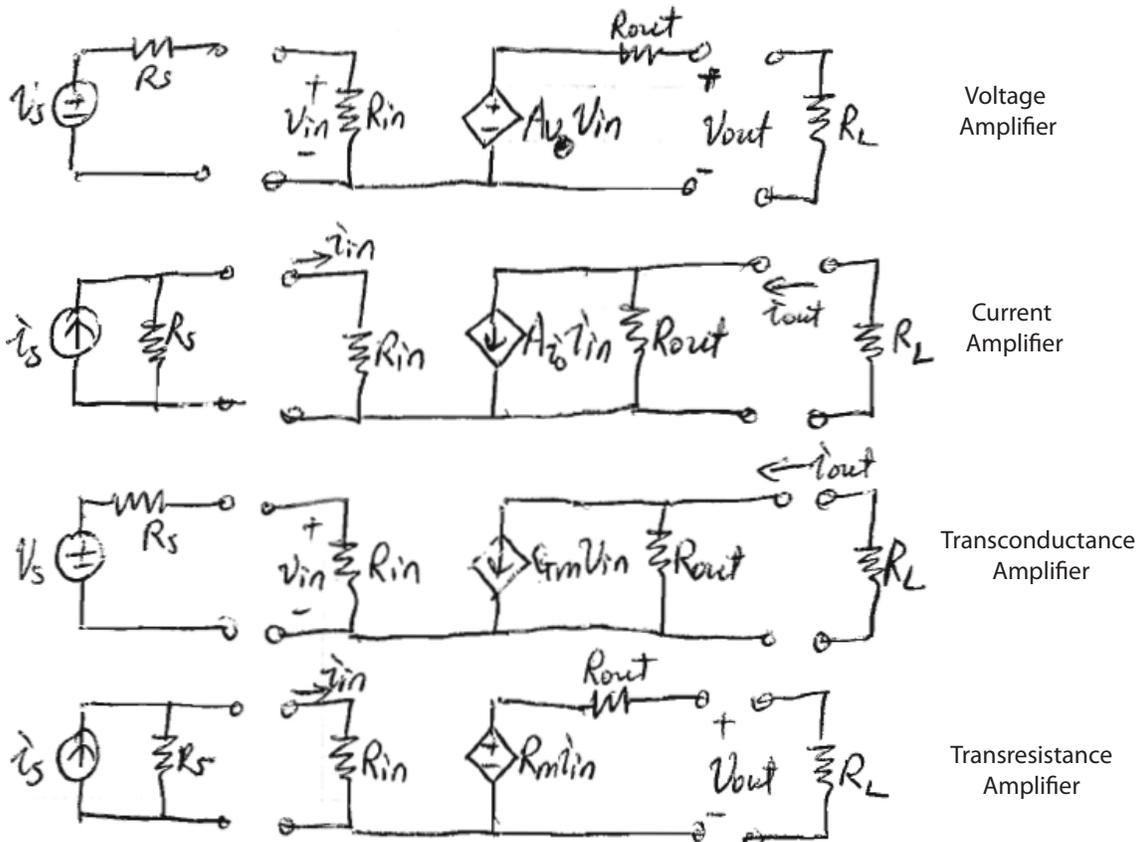


## Recitation 20: Amplifiers Review

Yesterday, we introduced two more amplifier circuits: C-drain, C-base.  
 As we know, there is an analogy between MOS & BJT:

MOS	BJT	Function
Common Source $\longleftrightarrow$	Common-Emitter	Voltage or $G_m$ Amp.
Common Drain $\longleftrightarrow$	Common-Collector	Voltage Buffer
Common Gate $\longleftrightarrow$	Common-Base	Current Buffer

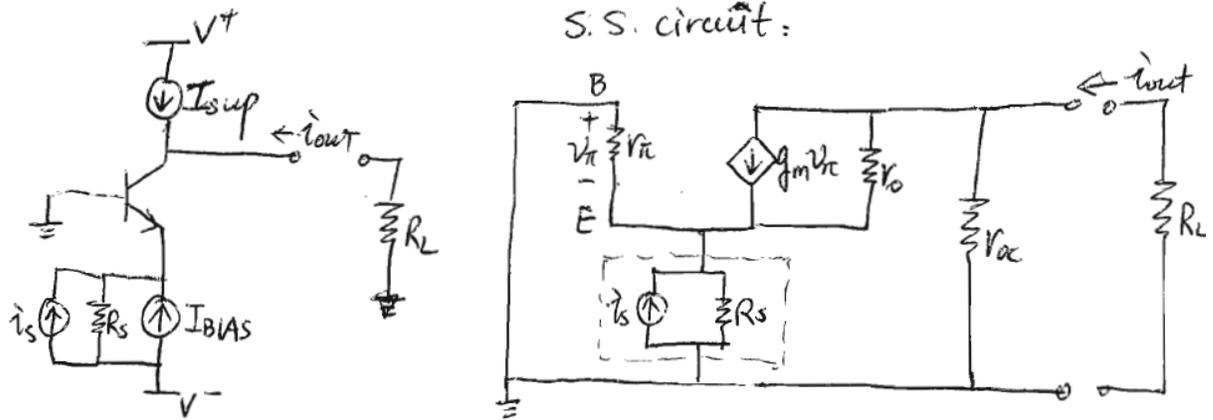
Note: Buffer is an amplifier with gain 1, but input or output impedance changed  
 We have also learned that there are 4 types of amplifiers, their *two port models* are



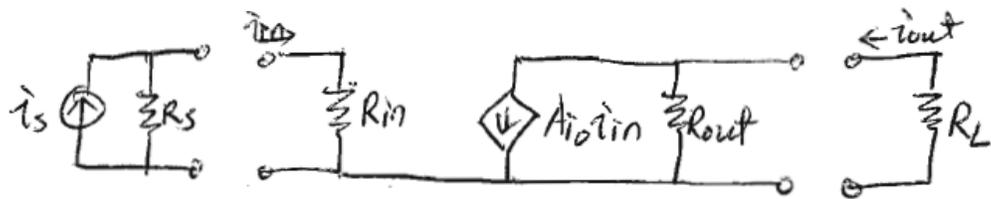
For the above single stage amplifiers (i.e. CS, CD, CG, CE, CC, CB), as we identify their particular function, e.g. current buffer is a type of current amplifier. We can use a *two-port model* for current amplifier to model a CB or CG circuit. Their corresponding  $R_{in}$ ,  $R_{out}$ ,  $A_{i0}$  will depend on the circuit (or device parameter), which we can derive based on the *small signal circuit model* of the circuit.

Yesterday, we looked at the example of CD & CG. Today we will look at CC & CB.

### Common-Base Amplifier



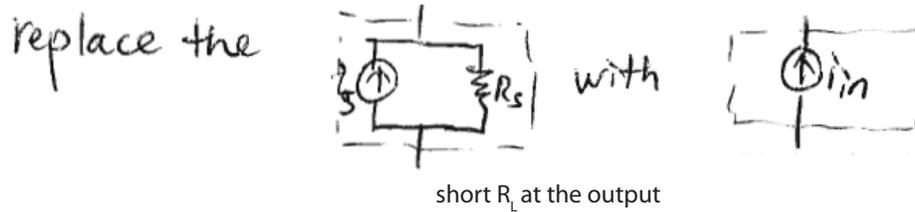
Cast this into two port model



Need to find what is the corresponding  $A_{io}$ ,  $R_{in}$ ,  $R_{out}$

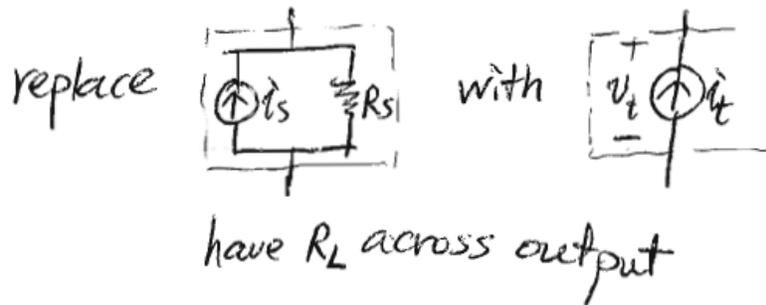
$A_{io}$

Intrinsic current gain: ignore  $R_s$ , just consider  $i_{in} = i_s$ ;  $R_L$  short.



$$\begin{aligned}
 i_{\text{in}} &= -\left(\frac{v_{\pi}}{\gamma_{\pi}} + g_m v_{\pi} + \frac{v_{\pi}}{\gamma_o}\right), \quad i_{\text{out}} = g_m v_{\pi} + \frac{v_{\pi}}{\gamma_o} \\
 \Rightarrow v_{\pi} &= -\frac{i_{\text{in}}}{\frac{1}{v_{\pi}} + g_m + \frac{1}{\gamma_o}} = \frac{i_{\text{in}}}{g_{\pi} + g_m + g_o} \\
 \Rightarrow A_{\text{io}} &= \frac{i_{\text{out}}}{i_{\text{in}}} = -\frac{(g_m + g_o) \cdot \frac{i_{\text{in}}}{g_{\pi} + g_m} + g_o}{i_{\text{in}}} = -\frac{g_m + g_o}{g_{\pi} + g_m + g_o} \simeq -1 \\
 \therefore \frac{1}{g_m} &\simeq 1 \text{ k}\Omega, \quad \gamma_o \approx 100 \text{ k}\Omega \\
 g_m \gg g_o, \quad \gamma_{\pi} &= \frac{\beta_F}{g_m} \Rightarrow g_{\pi} = \frac{g_m}{\beta_F} \quad g_{\pi} \ll g_m
 \end{aligned}$$

$R_{\text{in}}$



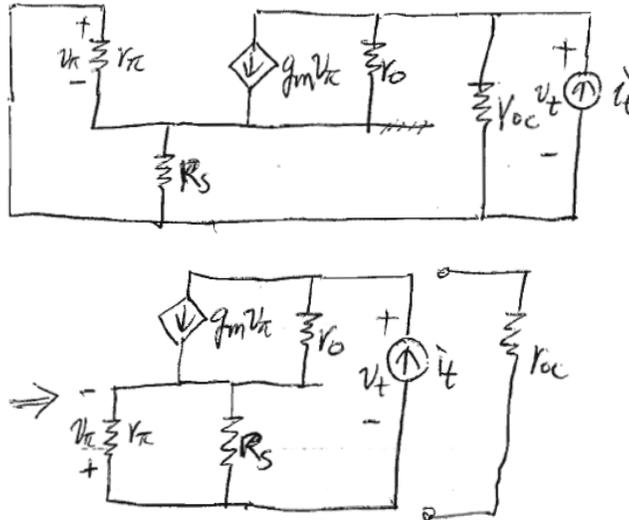
$$\begin{aligned}
 \gamma_{\pi}, \gamma_o &\gg \frac{1}{g_m} \quad \text{as we just discussed} \\
 \therefore &\text{transconductance generator } g_m \text{ dominates currents at the input node} \\
 i_t &= -\left(\frac{v_{\pi}}{\gamma_{\pi}} + g_m v_{\pi} + \frac{v_o}{\gamma_o}\right) \simeq -g_m v_{\pi} = g_m v_t \\
 \therefore R_{\text{in}} &= \frac{v_t}{i_t} = \frac{v_t}{g_m v_t} \simeq \frac{1}{g_m} \quad \text{LOW! (good for getting current in)}
 \end{aligned}$$

Exact: see pp 150 
$$R_{\text{in}} = \frac{1}{\frac{1}{\gamma_{\pi}} + g_m + \frac{1 - g_m(\gamma_{\text{co}} || R_L)}{\gamma_o + (V_{\text{oc}} || R_L)}}$$

$R_{out}$

Similarly

1. shut down all independent sources
2. load input with  $R_s$
3. put test current source at output
4.  $R_{out} = \frac{v_t}{i_t}$



$$i_t = g_m v_\pi + \frac{v_t + v_\pi}{\gamma_o} \quad \text{voltage across } \gamma_o \text{ is } v_t + v_\pi \quad (1)$$

$$v_\pi = -i_t \cdot (\gamma_\pi || R_s) \quad (2)$$

$$\Rightarrow \text{plug (2) into (1)} \quad (3)$$

$$i_t = \frac{v_t / \gamma_o}{1 + \frac{\gamma_\pi || R_s}{\gamma_o} + g_m (\gamma_\pi || R_s)} \quad (4)$$

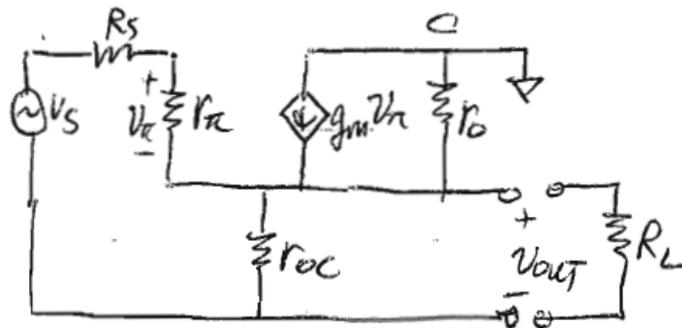
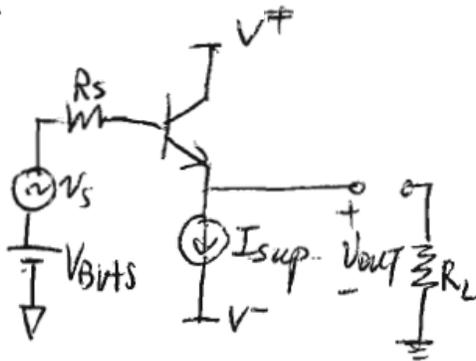
$$\Rightarrow \frac{v_t}{i_t} = \gamma_o + (\gamma_\pi || R_s) + g_m \gamma_o (\gamma_\pi || R_s) \quad (5)$$

$$\therefore R_{out} = \gamma_{oc} || [\gamma_o + (\gamma_\pi || R_s) + g_m \gamma_o (\gamma_\pi || R_s)] \simeq \gamma_{oc} || \gamma_o [1 + g_m (\gamma_\pi || R_s)] \quad (6)$$

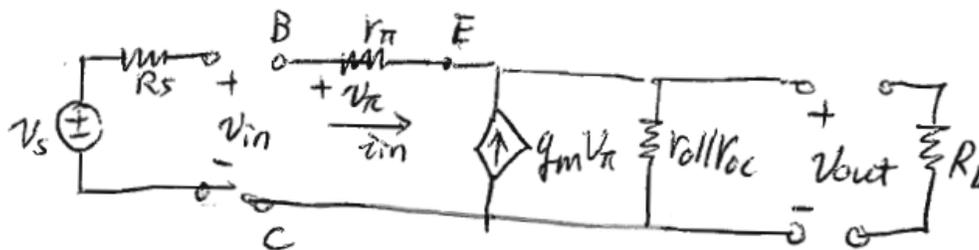
$$\text{If } R_s \gg \gamma_\pi, \quad R_{out} \simeq \gamma_{oc} || \gamma_o \underbrace{[1 + \underbrace{g_m \gamma_\pi}_{\beta_F}]}_{\text{large}} \quad (7)$$

Excellent current buffer: can use current source with source resistance only slightly higher than  $R_{in} \left( \frac{1}{g_m} \right)$ , and get same current with high  $R_{out}$

### Common-Collector Amplifier



Rearrange,



Cast this into two port voltage amplifier model

$$A_{vo}(R_L = \infty, R_s = 0)$$

$$V_{out} = A_{vo}V_{in} = \left( g_m v_\pi + g_m \frac{v_\pi}{\beta_F} \right) \cdot (\gamma_o || \gamma_{oc})$$

$$= g_m \left( 1 + \frac{1}{\beta_F} \right) v_\pi (\gamma_o || \gamma_{oc})$$

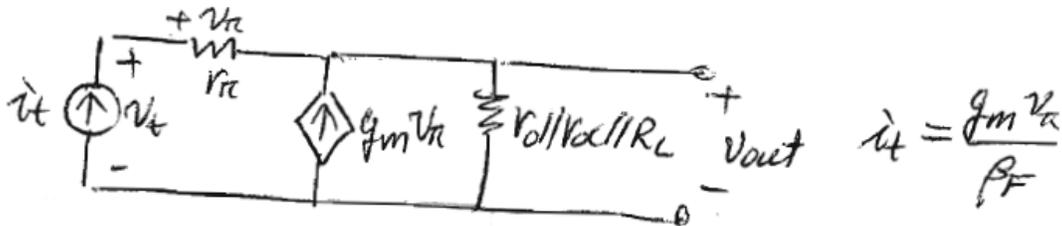
$$i_{in} = \frac{v_\pi}{\gamma_\pi} = v_\pi \frac{g_m}{\beta_F}$$

$$\text{But } v_\pi = v_{in} - v_{out} \implies v_{out} = g_m \left( 1 + \frac{1}{\beta_F} \right) (v_{in} - v_{out}) (\gamma_o || \gamma_{oc})$$

$$A_{vo} = \frac{v_{out}}{v_{in}} = \frac{1}{1 + \frac{1}{g_m} \left( 1 + \frac{1}{\beta_F} \right) (\gamma_o || \gamma_{oc})} \simeq 1$$

$R_{in}$

Leave  $R_L$  in place, replace source with



$$v_t = i_t \cdot \gamma_\pi + (i_t + g_m v_\pi) \cdot (\gamma_o || \gamma_{oc} || R_L)$$

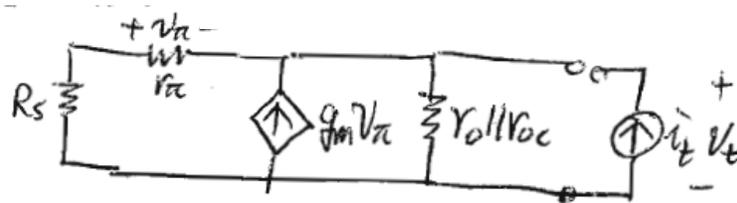
$$= i_t v_\pi + g_m \left( 1 + \frac{1}{\beta_F} \right) v_\pi (\gamma_o || \gamma_{oc} || R_L)$$

$$R_{in} = \frac{v_t}{i_t} = \gamma_\pi + \frac{g_m \left( 1 + \frac{1}{\beta_F} \right) v_\pi (\gamma_o || \gamma_{oc} || R_L)}{g_m \frac{v_\pi}{\beta_F}}$$

$$= \gamma_\pi + (\beta_F + 1)(\gamma_o || \gamma_{oc} || R_L) \quad \text{much larger than } \gamma_\pi$$

$R_{out}$

$v_s = 0$ , leave  $R_s$ , apply  $v_t, i_t$  at the output



$$\begin{aligned}
 & \ll \text{than } g_m v_\pi \\
 (i_t + g_m v_\pi + \underbrace{\frac{v_t}{\gamma_\pi}}_{\text{voltage divider}}) \cdot (\gamma_o || \gamma_{oc}) &= v_t \\
 \text{voltage divider } v_\pi &= -\frac{\gamma_\pi}{\gamma_\pi + R_s} \cdot v_t \\
 \Rightarrow i_t &= -g_m v_\pi + \frac{v_t}{\gamma_o || \gamma_{oc}} \\
 \Rightarrow i_t &= \frac{g_m \gamma_\pi}{\gamma_\pi + R_s} \cdot v_t + \frac{v_t}{\gamma_o || \gamma_{oc}} = \left( \frac{\beta_F}{\gamma_\pi + R_s} + \frac{1}{\gamma_o || \gamma_{oc}} \right) v_t \\
 \therefore i_t &\simeq \frac{\beta_F}{\gamma_\pi + R_s} v_t \\
 R_{out} &= \frac{v_t}{i_t} = \frac{\gamma_\pi + R_s}{\beta_F} = \frac{1}{g_m} + \frac{R_s}{\beta_F} \quad \text{LOW! } \because g_m, \beta_F \text{ large}
 \end{aligned}$$

In conclusion, see the summary sheet handout

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